

Improvement Test

Sub: Basic Electronics

Code: 15ELN25

Date: 29/05/2017

Duration: 90 mins

Max Marks: 50

Sem: II

Sections:- A,B,C, D, E, F and G

Answer any FIVE FULL questions.

Marks

OBF

RBT

[10]

C04 L2

[10]

C05 L2

[5+5]

C05 L2

[5+5]

C06 L2

1. Explain the architecture of 8051 microcontroller with neat diagram.

2. Derive AM wave expression with relevant waveforms. Also, draw frequency spectrum and calculate the bandwidth of AM signal.

3. Derive the total power transmitted by an AM wave. A 1000 W, 1 MHz carrier is amplitude modulated with a sinusoidal signal of 1 KHz. The depth of modulation is 50%. Calculate the bandwidth, power in the sidebands and the total transmitted power.

4. Explain the working of Thermistor and LVDT along with suitable diagram.

5. List the differences between AM and FM signals.

[10] C05 L2

6. Write a short note on i) AM demodulator ii) Working of stepper motor.

[5+5] C05 L2

7. Explain the structure of PSW and internal RAM of 8051.

[5+5]

C04 L2

Basic Electronics

Evaluation Scheme-IAT-3

29 May, 2017

Section - A, B, C, D, E, F and G

Ans-1

Architecture diagram - 4 marks
Explanation - 6 marks.

Ans-2

AM wave derivation - 4 marks
Waveform - 2 marks
Frequency spectrum - 2 Marks
Bandwidth - 2 Marks.

Ans-3

Derivation Total Power = 5 marks

{ Bandwidth = 1 Mark
P_{USB} = 1 Mark
P_{LSB} = 1 Mark
P_T = 2 Mark

Ans-4

Thermistor Explanation - 4 Mark } (5)
diagram - 1 Mark

LVDT Explanation - 4 mark } (5)
diagram - 1 Mark

Ans-5

5 Difference - 10 Marks

Ans-6

Diagram AM - 1 } (5)
Explanation - 4

stepper Motor dia - (1)
Working - (4)

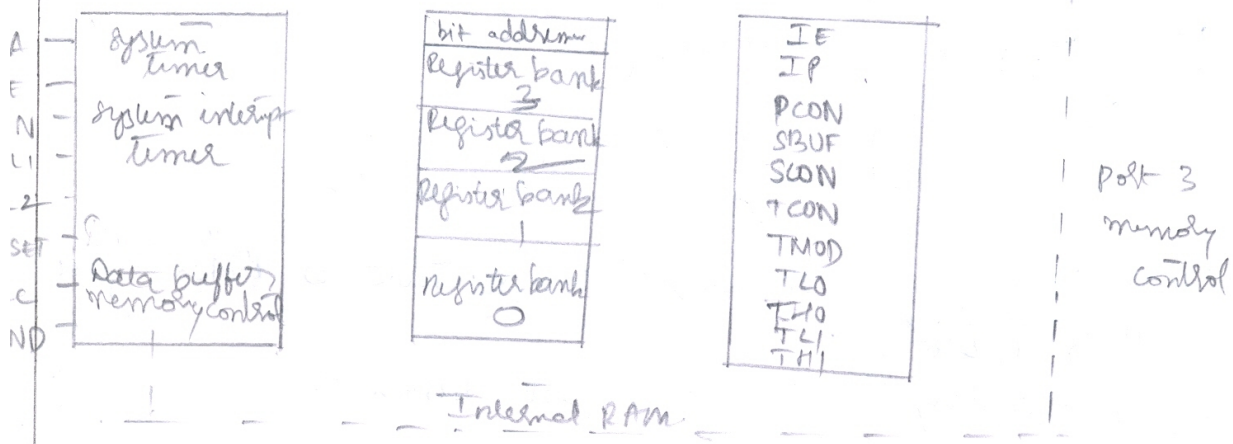
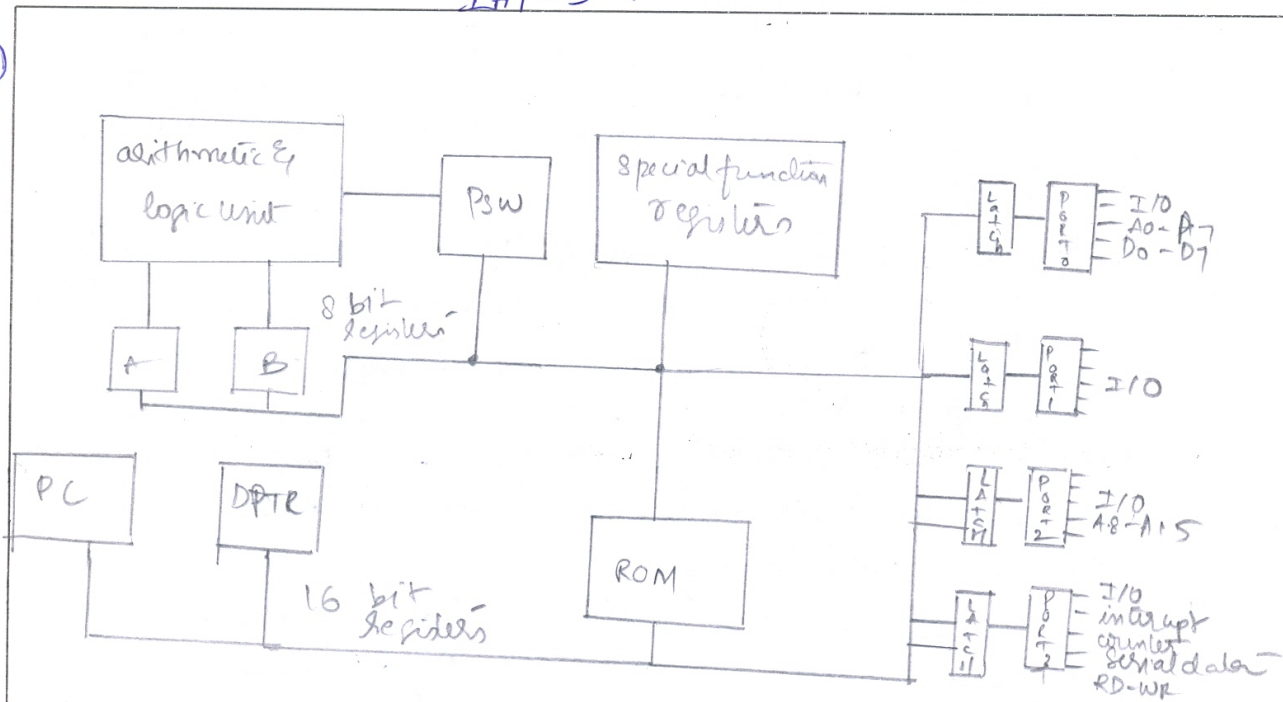
Ans-7

PSW → 5 Marks , RAM → 5 Marks



IAT-3

D



port 3
memory
control

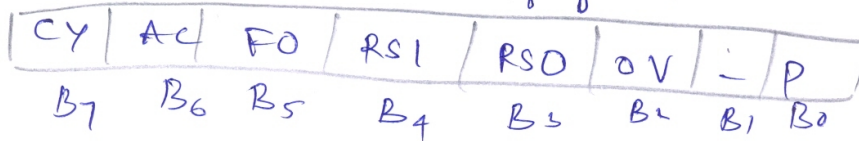
Register A :- It is an 8 bit register. It is also called as an accumulator. It holds the source operand & receives the result of arithmetic operation like addition, subtraction, division & multiplication.

Register B :- It is an 8 bit register & an accumulator. It is used for the operation of division & multiplication.

Data pointer :- It is an 16 bit register. It has a capacity to hold 16 bits. It can hold low byte as well as high byte addresses. It ~~prova~~ acts as a base register for indirect jumps & look up table & external data transfer.

Program Counter :- It is also an 16 bit register. It is used to hold the address of external memory location from which the information is fetched.

PSW :- It is also called as flag register:



CY → carry flag :- It is set when there is over flow out of 7 bit.

AC → Auxiliary flag :- It is set when there is over flow out of 3 bit.

RS1 & RSD

FO → It is defined by user for general purpose.

RS1 & RSD	RS1	RSD	Bank selected	
	0	0	Bank 0	00H - 0FH 00H - 07H
	0	1	Bank 1	08H - 0FH
	1	0	Bank 2	10H - 17H
	1	1	Bank 3	18H - 1FH



OV ^{overflow} → overflow flag: - It is set when there ^{is} the signed number operation is large, ^{when} the high bit goes into sign bit.

P → Parity flag: - It is determined by the number of ones present in the accumulator. If $P=1$ then the number of ones present in the accumulator is odd. If $P=0$ then the number of ones present in the accumulator are even.

Ports:

Port 0: - Pins of port 0 can be used as I/O. Output drives E_0 input buffers can be used to access the external memory data. Port 0 outputs low byte of external memory address.

Port 1: - It is used as I/O.

Port 2: - ~~The~~ The pins of port 2 can be used to access the external memory data. Outputs high byte of external memory address.

Port 3: - The pins of port-3 are multifunctional. It can be used for I/O or for some other alternate function.

~~Vcc~~ Vcc & Vss: - +5V is connected to Vcc & grounded to Vss pin.

~~Crystal oscillator pins~~: XTAL1, XTAL2: - 8051 generates in order to generate internal clock signal.



3 (a) $P_T = P_C + P_{USB} + P_{LSB}$

$$P_T = \frac{V_c^2}{R} + \frac{V_{USB}^2}{R} + \frac{V_{LSB}^2}{R}$$

$$P_T = \left(\frac{V_c}{\sqrt{2}}\right)^2 \frac{1}{R} + \left(\frac{\frac{mV_c}{2}}{\sqrt{2}}\right)^2 \frac{1}{R} + \left(\frac{\frac{mV_c}{2}}{\sqrt{2}}\right)^2 \frac{1}{R}$$

$$= \frac{V_c^2}{2R} + \frac{m^2 V_c^2}{8R} + \frac{m^2 V_c^2}{8R}$$

$$P_T = \frac{V_c^2}{2R} + \frac{m^2 V_c^2}{4R}$$

$$= \frac{V_c^2}{2R} \left[1 + \frac{m^2}{2} \right]$$

$$= P_C \left[1 + \frac{m^2}{2} \right]$$

(b) $P_C = 1000W$, $f_c = 1MHz$, $f_m = 1kHz$
 $m = 0.5$, B.W = ?, $P_{USB} \cdot P_{LSB} = ?$, $P_T = ?$

(c) $P_{L_{SB}} = 62.5W$

$P = P_{L_{SB}} + P_{U_{SB}} = 125W$

1) $P_T = P_c \left(1 + \frac{m^2}{2} \right)$
 $= 1000 \left[1 + \frac{(0.5)^2}{2} \right] = \underline{\underline{1125W}}$

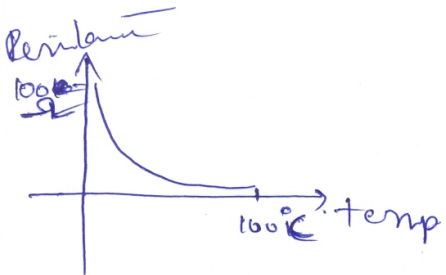
4) a Thermistor :-

- (1) ~~To determine the ch~~
- (1) Temperature changes in terms of resistance.
- (2) The sensitive element is made up of solid particles.
- (3) The sensitivity for the conductor ~~is~~ ~~semi~~ increases with \uparrow in temp where as for semiconductor & insulators \downarrow as Temp \uparrow .


working principle :- It is used to determine the resistance change in order to determine temp changes.


$R = R_0(1 + \alpha \Delta T)$ where $R \rightarrow$ resistance at $t^\circ C$
 $R_0 \rightarrow$ " " " $0^\circ C$

$\alpha \Delta T \rightarrow$ temp co-efficient
 $\Delta t \rightarrow$ change in temp.



They are available in various shapes & sizes. Thermistors are made up of sintered mixture of metallic oxides like manganese, nickel, iron etc.

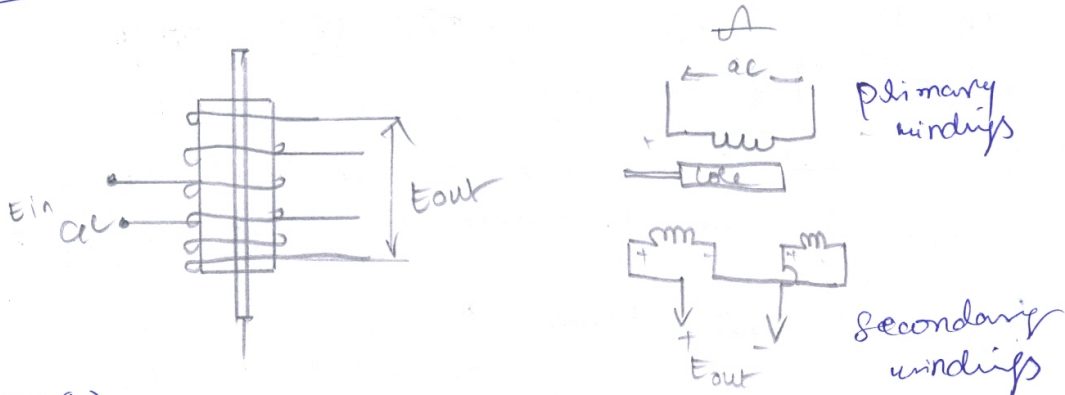
Beads:  These are small with a diameter of 0.15mm & 1.25mm.

Probes:  Beads are sealed into the tip of the solid glass rod to form probes.

disc:  rod  head.

disc & rods are made by pressing the thermistor at a very high pressure. Washers are connected in series & parallel for proper power dissipation.

LVDT: (Linear variable displacement transducer)



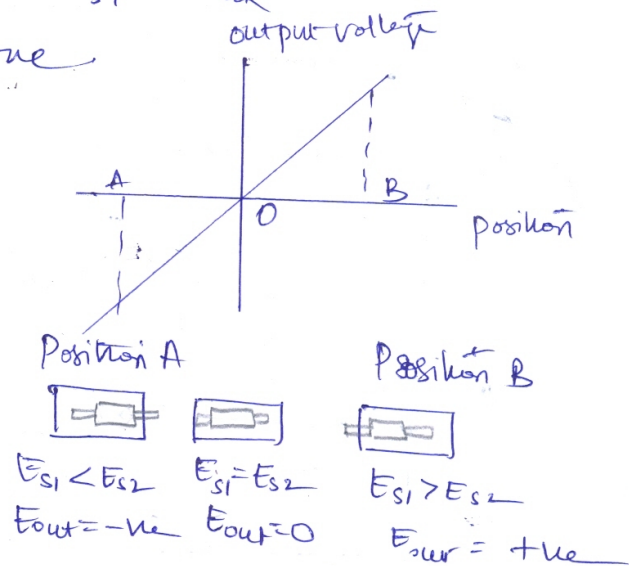
Case (i)

When an ac source is applied to primary winding with the core at the centre, the emf induced by the secondaries will become equal. $E_{s1} = E_{s2}$

Since they oppose each other the output voltages will become equal to zero.

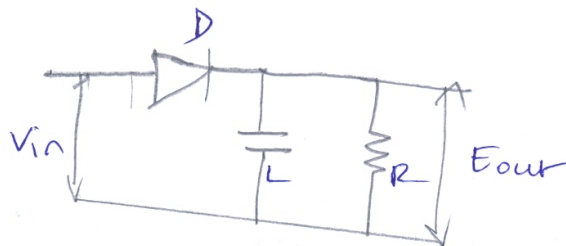
Case (i): when the core is moved towards the right side, flux links more on right hand coil than on left hand. $E_{s1} < E_{s2}$. Output voltage will be equal to negative.

Case (ii) when the core is moved towards the left side, flux links more on left hand coil than on right hand. $E_{s1} > E_{s2}$. Output voltage will be equal to the



6) a) AM demodulator:

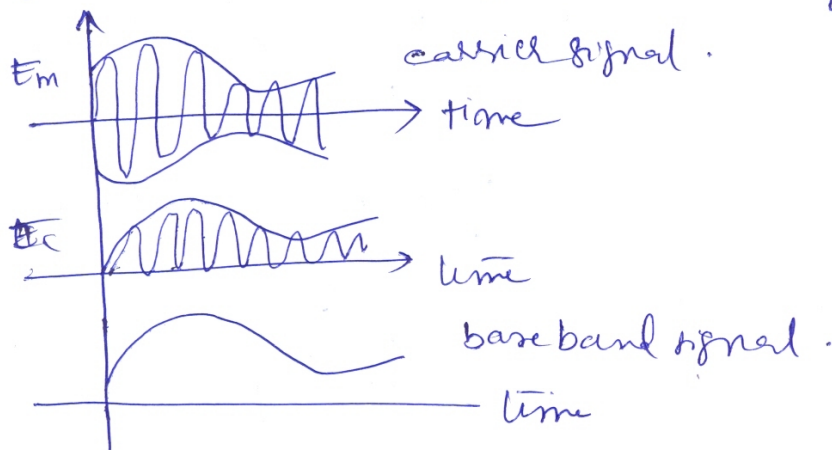
It is used to the part of the receiver which is used to restore the original signal or information.



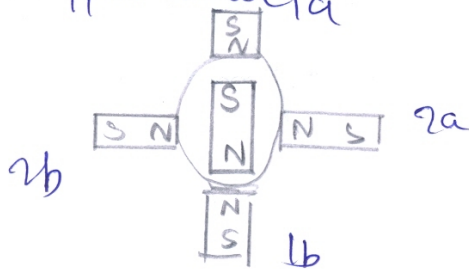
In this fig D acts as half wave rectifier diode & LR acts as a low pass filter.

During the +ve half cycle the AM signal diode conducts, the current flows through R. During the -ve half cycle the AM signal diode does not conduct as the result current doesn't flow through R.

Capacitor is connected in parallel with resistance. Capacitor provides low impedance for the carrier signal & high impedance for modulating signal. Thus capacitor filters the carrier signal & leaves the original modulating signal.



(ii) Stepper motor



When electrical signals are applied to the motor, the motor starts rotating at the speed at which the electrical signals are applied. The direction of rotation depends on the pattern of the

is called shaft which is surrounded by shaft. stator. There are 4 stator windings which are paired with center tapped common.

working principle - The center tap on stator windings produces the current in the coil which changes when the stepper windings are grounded. The magnetic property of stator changes & respectively attracts the repels the motor this results in stepper motion of the motor.

Single coil excitation

1a	2a	1b	2b	Position of motor
1	0	0	0	
0	1	0	0	
0	0	1	0	
0	0	0	1	
↑	0	0	0	










It completes its 1 revolution in 4 steps. Each steps are at angle of 90° .

Full step size excitation

1a	2a	1b	2b	Position of motor
1	1	0	0	
0	1	1	0	
0	0	1	1	
↑	0	0	1	
1	1	0	0	

It completes its 1 revolution in 4 steps. Each steps are at angle of 90° .

Half step size excitation

	1a	2a	1b	2b	Position of poles
1	1	0	0	0	
2	1	1	0	0	
3	0	1	0	0	
4	0	1	1	0	
5	0	0	1	0	
6	0	0	1	1	
7	0	0	0	1	
8	1	0	0	1	
9	1	0	0	0	

⑦ To complete 1 revolution it takes 8 steps. Each step is at the angle of 45° .

⑦ PSW:- It is also called as ~~PSW~~ flag register -

B ₇	B ₆	B ₅	B ₄	B ₃	B ₂	B ₁	B ₀
CY	AC	FO	RS1	RS0	OV	-	P

CY → Carry flag:-

It is set when there is over flow of 7 bit. It can also be used as borrow flag for subtraction.

AC → Auxillary flag:-

It is set when there is over flow of 3 bit i.e. carry from lower nibble to higher nibble.



FO \rightarrow It is defined by user for general purpose.

RS1 & RS0

RS1	RS0	Bank selection
0	0	Bank 0
1	1	Bank 1
1	0	Bank 2
1	1	Bank 3

00H - 07H
08H - 0FH
10H - 17H
18H - 1FH

OV \rightarrow overflow flag :-

It is set when there is the signed number operation is large, & when high bit goes into sign bit.

P \rightarrow Parity flag :-

It is determined by the number of ones which are present in the accumulator. If $P=1$, the number of ones which are present in accumulator are odd & if $P=0$, the number of ones which are present in the accumulator are even.

(b) Internal RAM of 8051

It consists of 3 types

- Register banks
- Bit/Byte addresses
- General purpose

(a) Register banks: - From first 32 bytes of ~~00H~~ 00H to 1FH of internal RAM constitute 32 registers.



RS1	RS0	Bank selection
0	0	Bank 0
0	1	Bank 1
1	0	Bank 2
1	1	Bank 3

(or)

RS1	RS0	Bank selection
0	0	Bank 3
0	1	Bank 2
1	0	Bank 1
1	1	Bank 0

(b) Bit / Byte addressing :- 8051 provides 16 bytes of addresses. It occupies ~~internal~~ RAM bytes of addresses 20H to 2FH.

(c) General purpose :- RAM area is above the bit address area whose address is of 30H to 7FH.

- (1) ALE :- A₀ to A₇ are multiplexed. In order to demultiplex these lines internal clock signal is used.
- RESET :- It is used to reset the entire microcontroller. The reset signal must be atleast of high ~~width~~ of two clock cycle machines.
- PSEN :- It is the active low output signal which is used to activate the enable signal of external ROM.
- EA :- EA is high when program fetches to addresses from 0000H to DFFFH to direct it to ~~external~~ internal ROM & fetches to addresses from ~~0000H~~ 1000H to FFFFH to direct it to external ROM. If EA is low the program fetches to address from 0000H to FFFFH to direct it to external ROM.